

**Support information for: Constructing ultra-stable and
high-performance zinc-ion batteries through Mn doped
vanadium oxide nanobelt cathode**

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Experimental Section

Materials preparation: The $\text{Mn}_x\text{VO}_2 \cdot 0.2\text{H}_2\text{O}$ was prepared with a simple solvothermal method. The Solvothermal solution was prepared by dissolving 0.6g V_2O_5 powder and 1.2g $\text{H}_2\text{C}_2\text{O}_4$ powder into 20 mL of distilled water at 85 °C for vigorous stirring about 3 h until $\text{VO}_2\text{C}_2\text{O}_4$ (dark blue solution) was formed. Then 4.67 mL 30 % H_2O_2 was slowly added (this step reacts violently) and kept continuously stirring about 30 min to obtain a brown solution, then 16 mg $\text{Mn}(\text{CH}_3\text{COO})_2 \cdot 4\text{H}_2\text{O}$ was finally added into above-mentioned solution to obtain the Mn-doped vanadium oxide solution and stirred for 10 min until it was totally dissolved. The mixture was then given a 60 mL ethanol addition, and stirring continued for 60 min. The created dark-green slurry was then put into a 100 mL Teflon-lined autoclave and heated to 170°C for 12 hours. The precipitate was then collected, carefully cleaned with ethanol and deionized water, and dried for 12 hours at 60°C.

We analyzed the samples with an X-ray diffractometer using Cu $K\alpha$ radiation ($\lambda = 0.1542$ nm). In order to determine the morphology and microstructure of the samples, scanning electron microscopy (SEM, Hitachi-4800) and transmission electron microscopy (TEM, JEM-2100 PLUS) were carried out. Chemical bond valences and elemental compositions of the cathode material surface were measured using X-ray photoelectron spectroscopy (XPS). A Bruker D8 Advance diffractometer was used to measure ex-situ XRD patterns of the samples.

The calculations are implemented in Vienna Ab-initio Simulation Package

of density functional theory, which use projector augmented wave method¹. The following valence electron configurations are used: O($1S^22S^22P^4$), V($(1S^22S^22P^63S^23P^64S^23d^3)$), Mn($1S^22S^22P^63S^23P^64S^23d^5$) and Zn($1S^22S^22P^63S^23P^64S^23d^{10}$). We select generalized gradient approximation (PBE flavor) as exchange-correlation potential². Brillouin zone integrations are used for geometry optimization and electronic structure calculations, performing on $2 \times 2 \times 3$ k-meshes. The energy criterion, iterative solution of the kohn-sham equations is set to 10^{-5} eV. A cut-off energy of plane wave basis is performed 450 eV, which is decided to yield converged results. On the atoms, the residual force is set to 0.03 eV/Å. When it less than 0.03 eV/Å, the structures will be relaxed.

An active electrode was prepared by mixing acetylene black, polytetrafluoroethylene emulsion, and active materials in a weight ratio of 2:1:7. Then upon rolling the mixture into a uniform thickness, which was pressed onto conductive carbon paper with a diameter of 1 cm. The active materials were loaded at an average mass of 1.3 mg/cm². A solution of Zn(CF₃SO₃)₂ was used as the electrolyte. The electrochemical characteristics and electrochemical reaction kinetics analysis of the coin cells were tested using an electrochemical workstation (Bio-Logic VSP-300). Galvanostatic charge-discharge cycling was carried out using multichannel galvanostatic testers (Neware CT-4000).

TableS1. ICP test results

Sample label	Element label	Weight /g	volume ml	Dilution coefficient	Instrument reading mg/L	Sample concentration	Unit
Yan Chen	Mn	0.0546	50	50	0.448	20512.7365	mg/kg
Yan Chen	V	0.0546	50	50	11.4468	524120.7064	mg/kg

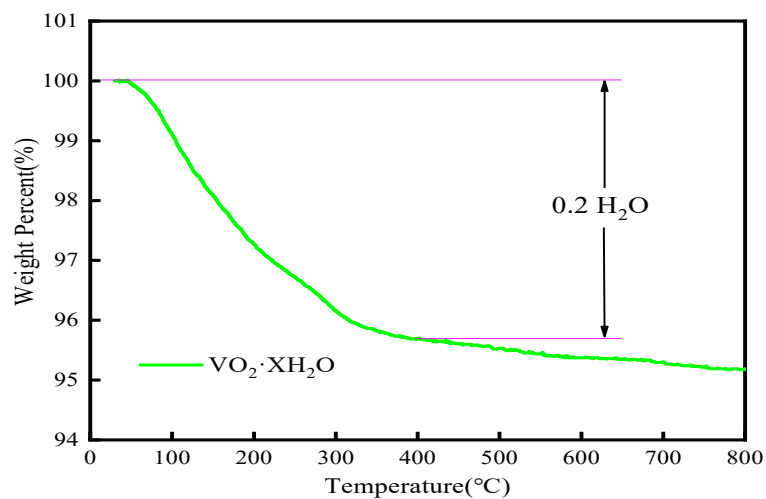


Figure S1. Thermogravimetric Curve of $\text{VO}_2 \cdot 0.2\text{H}_2\text{O}$

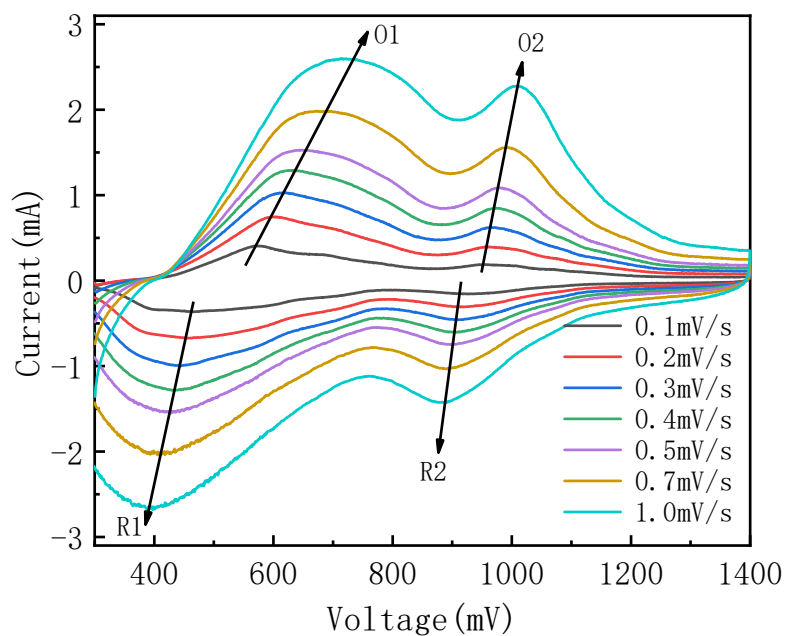


Figure S2. CV curves of $\text{VO}_2 \cdot 0.2\text{H}_2\text{O}$ at different scan rates

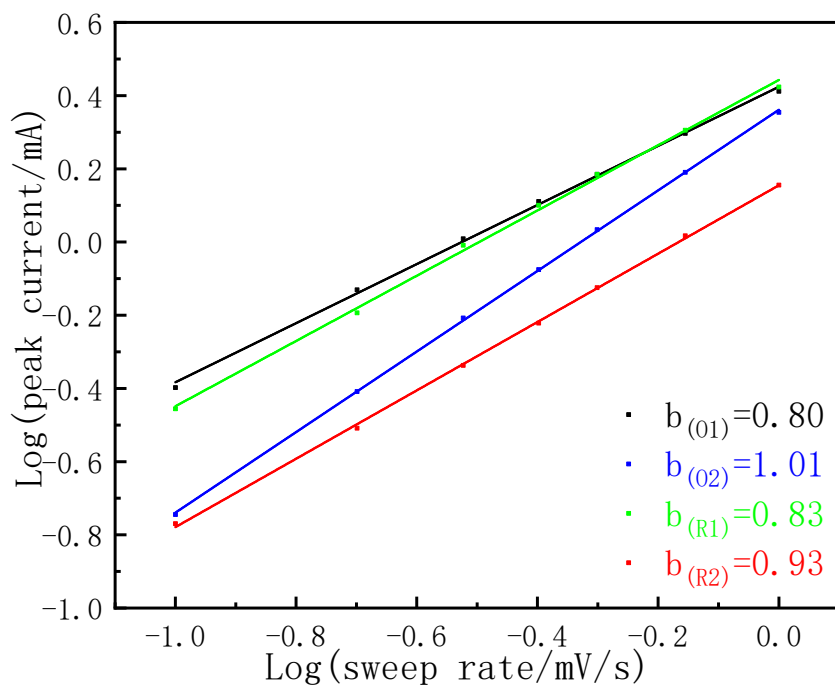


Figure S3. Log (i, current) versus log (mV, scan rate) plots of $\text{VO}_2 \cdot 0.2\text{H}_2\text{O}$ at specific current.

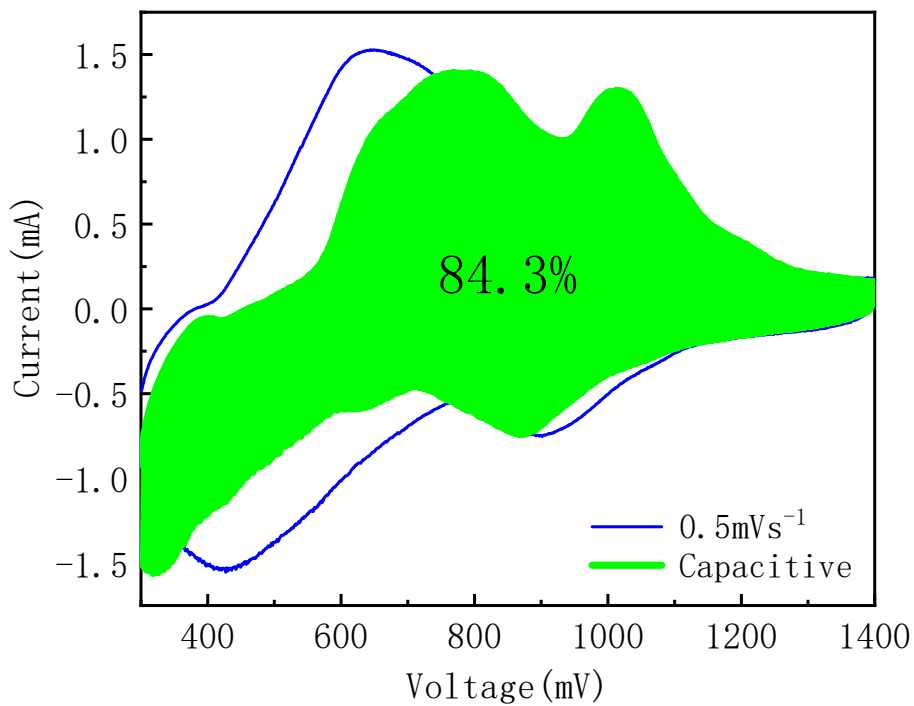


Figure S4. The capacitive contribution ratio of $\text{VO}_2 \cdot 0.2\text{H}_2\text{O}$ at 0.5 mVs^{-1} scan rates

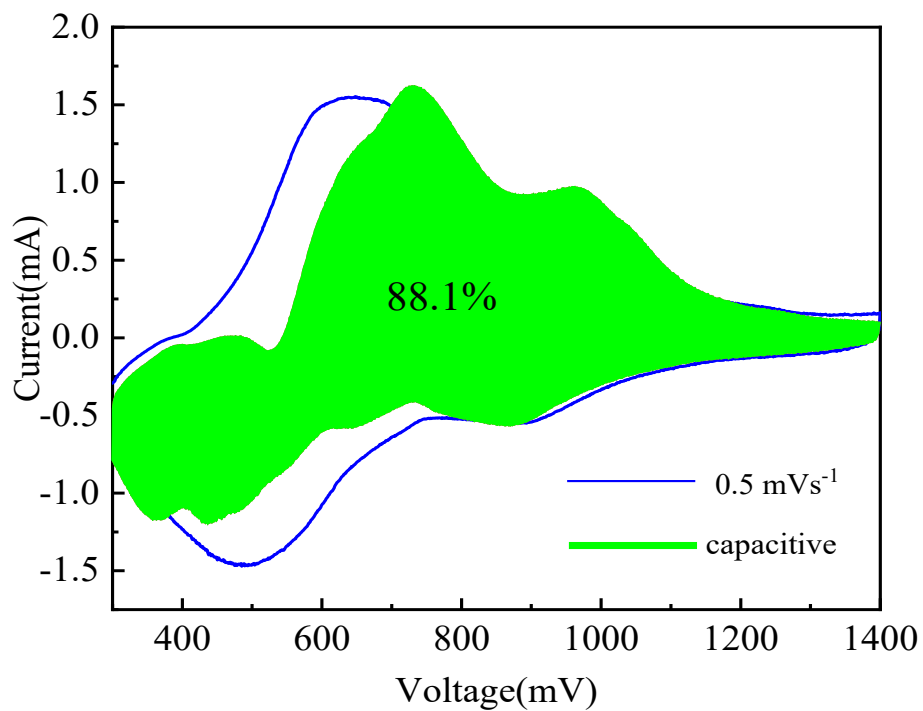


Figure S5. The capacitive contribution ratio of $\text{Mn}_x\text{VO}_2 \cdot 0.2\text{H}_2\text{O}$ at 0.5 mVs^{-1} scan rates

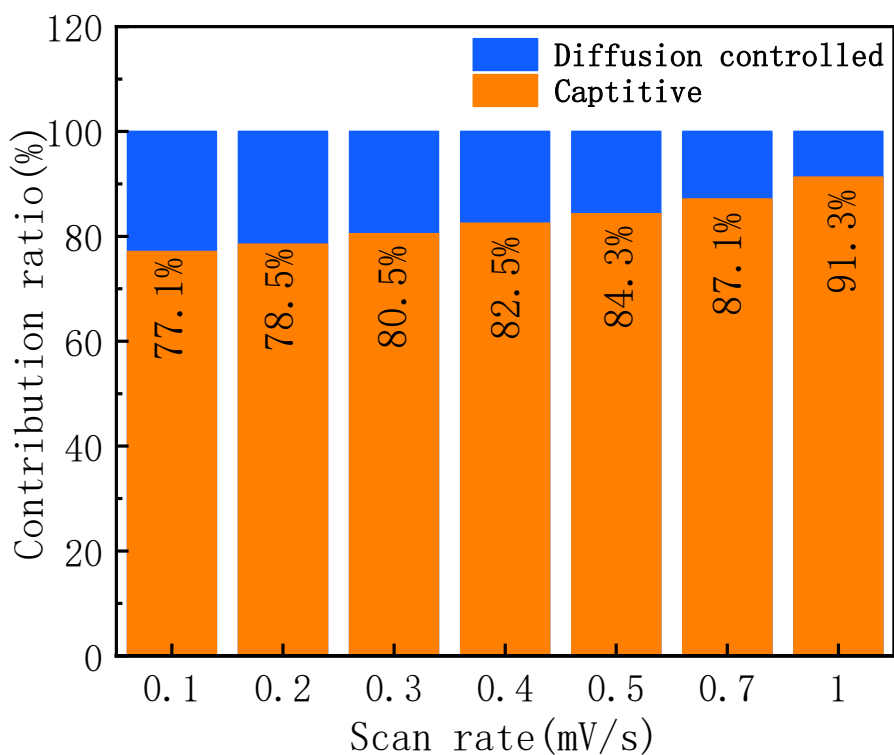


Figure S6. The capacitive contribution ratio of $\text{VO}_2 \cdot 0.2\text{H}_2\text{O}$ at various scan rate

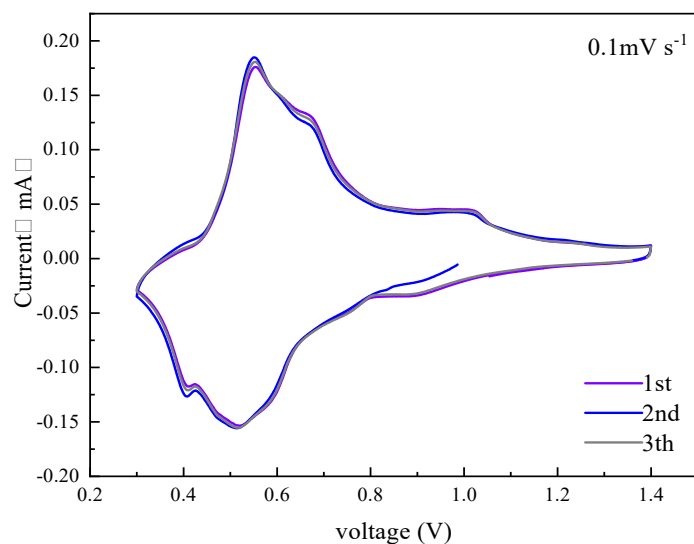


Figure S7. CV curves of $\text{VO}_2 \cdot 0.2\text{H}_2\text{O}$ collected at a scan rate of 0.1 mV s^{-1} .

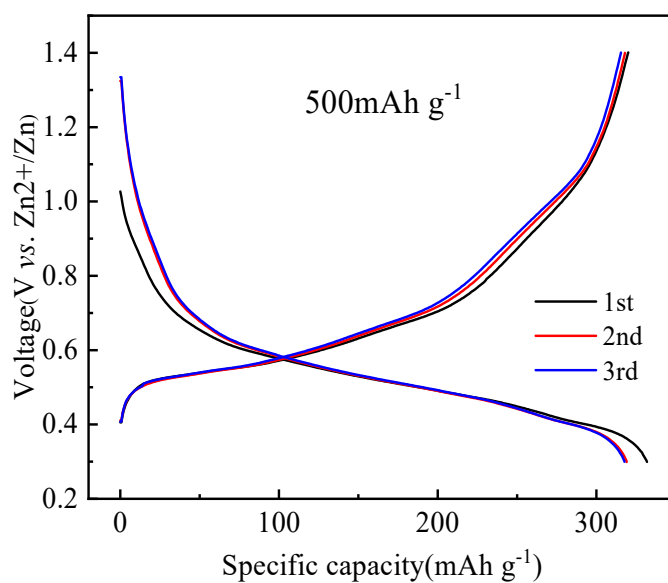


Figure S8. The first three discharge-charge profiles of $\text{VO}_2 \cdot 0.2\text{H}_2\text{O}$ at a current density of 500 mAh g^{-1} .

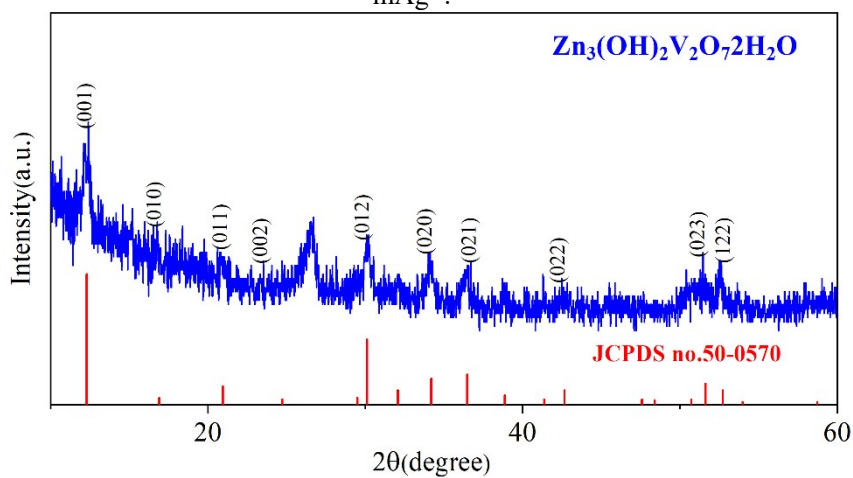


Figure S9. XRD patterns of $\text{Mn}_x\text{VO}_2 \cdot 0.2\text{H}_2\text{O}$ electrode sheet after 500 cycles

Table S2. Electrochemical impedance spectra of $\text{Mn}_x\text{VO}_2 \cdot 0.2\text{H}_2\text{O}$ and $\text{VO}_2 \cdot 0.2\text{H}_2\text{O}$

	$\text{Mn}_x\text{VO}_2 \cdot 0.2\text{H}_2\text{O}$ Pristine electrode	$\text{VO}_2 \cdot 0.2\text{H}_2\text{O}$ Pristine electrode	$\text{Mn}_x\text{VO}_2 \cdot 0.2\text{H}_2\text{O}$ 10 cycles	$\text{VO}_2 \cdot 0.2\text{H}_2\text{O}$ 10 cycles
Equivalent circuit diagram				
R2(Ω)	9.68	18.96	36.52	67.14
R1(Ω)	2.23	2.76	2.14	2.21

Table S3. The integral of the ICOHP

COHP# Zn- $\text{Mn}_{0.04}\text{VO}_2$	atom	atom	distance	ICOHP
Spin up	V17	O89	2.20497	-1.96883
Spin down	V17	O89	2.20497	-2.02170

COHP# Zn- VO_2	atom	atom	distance	ICOHP
Spin up	V15	O87	2.08418	-1.77492
Spin down	O15	V87	2.08418	-1.83334

Reference

- (1) Enkovaara, J.; Rostgaard, C.; Mortensen, J. J.; Chen, J.; Dułak, M.; Ferrighi, L.; Gavnholt, J.; Glinsvad, C.; Haikola, V.; Hansen, H., Electronic structure calculations with GPAW: a real-space implementation of the projector augmented-wave method. *Journal of physics: Condensed matter* **2010**, *22* (25), 253202.
- (2) Perdew, J. P.; Burke, K.; Ernzerhof, M., Generalized gradient approximation made simple. *Physical review letters* **1996**, *77* (18), 3865.